**Pb Free Product** 

# **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

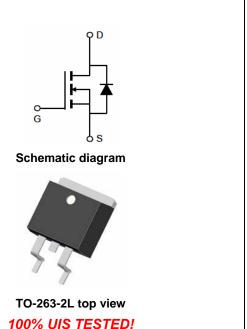
The NCEP85T14D uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

- $V_{DS}$  =85V, $I_{D}$  =140A  $R_{DS(ON)}$  <4.0mΩ @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

#### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



100% ΔVds TESTED!

#### **Package Marking and Ordering Information**

D	evice Marking	Device	Device Package	Reel Size	Tape width	Quantity
ı	NCEP85T14D	NCEP85T14D	TO-263-2L	-	-	-

#### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	85	V
Gate-Source Voltage	V <sub>G</sub> S	±20	V
Drain Current-Continuous	I <sub>D</sub>	140	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	99	Α
Pulsed Drain Current	I <sub>DM</sub>	420	А
Maximum Power Dissipation	P <sub>D</sub>	200	W
Derating factor		1.3	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1000	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>θJC</sub>	0.75	°C/W	
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# NCEP85T14D

## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	85		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =85V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.0	3.1	4.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =70A	-	3.3	4.0	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =70A	50	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	14 401/11 01/	-	5600	-	PF
Output Capacitance	Coss	$V_{DS}$ =40V, $V_{GS}$ =0V, F=1.0MHz	-	850	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVIHZ	-	60	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	20	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =40 $V$ , $I_D$ =70 $A$	-	10	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =4.7 $\Omega$	-	30	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	35	-	nS
Total Gate Charge	Qg	\/ 40\/ L 70A	-	84		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=40V, I_{D}=70A,$	-	30.6		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	18.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =140A	-		1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	140	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C$ , $I_F = I_S$	-	83		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	194		nC

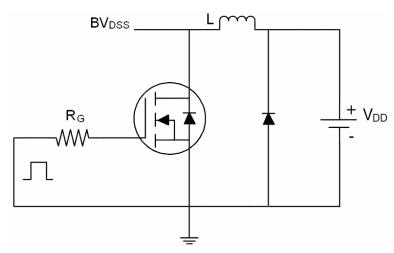
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=42.5V,VG=10V,L=0.5mH,Rg=25 $\Omega$

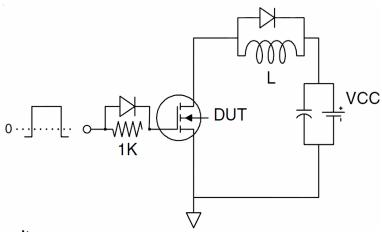


### **Test Circuit**

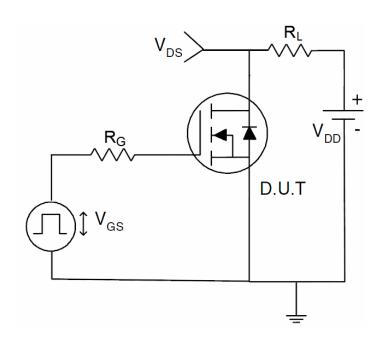
## 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

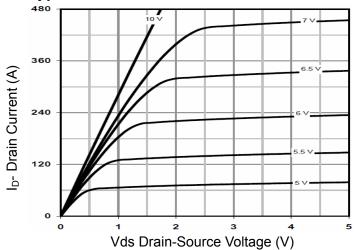


## 3) Switch Time Test Circuit

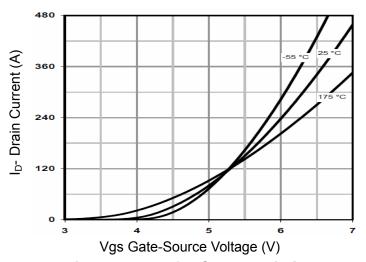




#### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

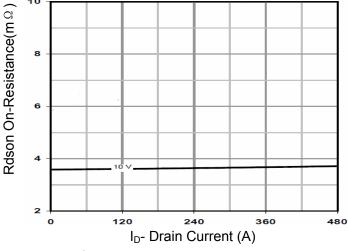


Figure 3 Rdson- Drain Current

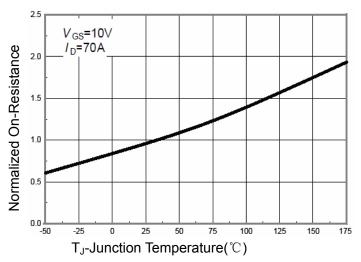


Figure 4 Rdson-JunctionTemperature

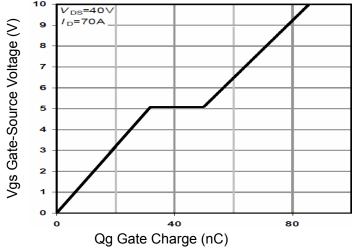


Figure 5 Gate Charge

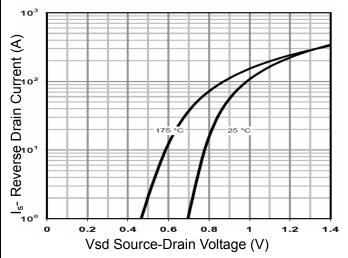
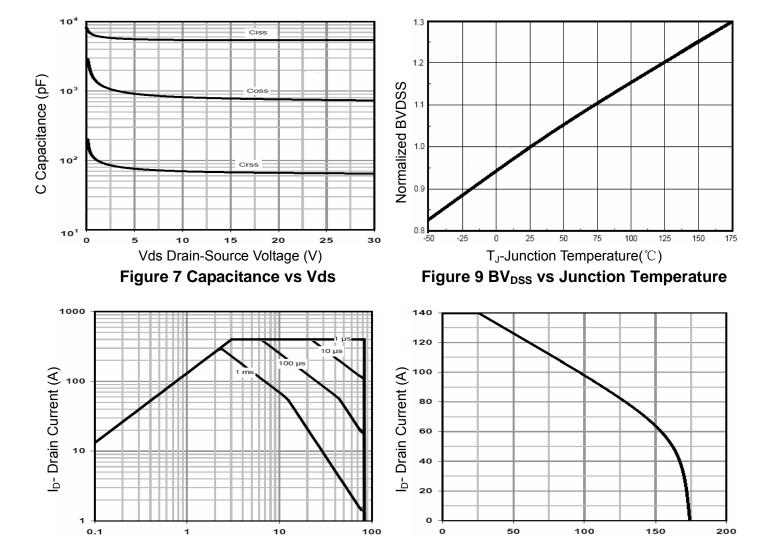


Figure 6 Source- Drain Diode Forward

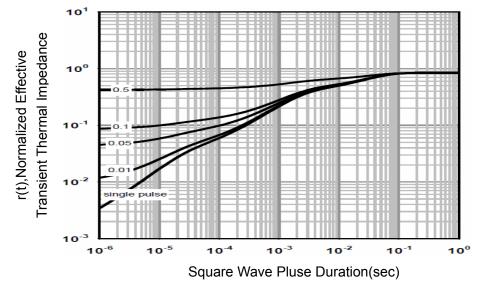






T<sub>J</sub>-Junction Temperature(°C)

Figure 10 Current De-rating



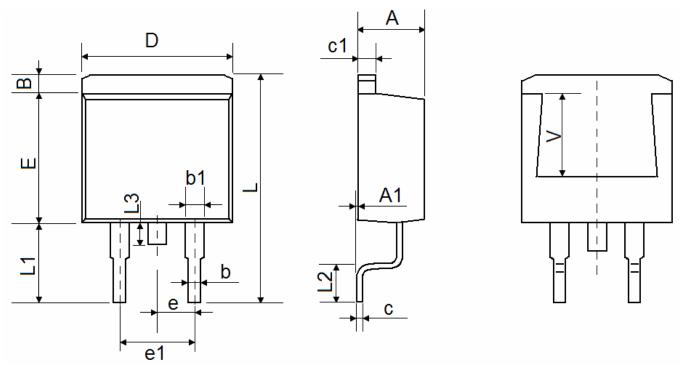
**Figure 11 Normalized Maximum Transient Thermal Impedance** 

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# NCEP85T14D

# **TO-263-2L Package Information**



Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.470	4.670	0.176	0.184	
A1	0.000	0.150	0.000	0.006	
В	1.170	1.370	0.046	0.054	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
E	8.500	8.900	0.335	0.350	
е	2.540	TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
L	15.050	15.450	0.593	0.608	
L1	5.080	5.480	0.200	0.216	
L2	2.340	2.740	0.092	0.108	
L3	1.300	1.700	0.051	0.067	
V	5.60	0 REF	0.220 REF		



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# NCEP85T14D

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